## Ultra-Low $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ <br> IGBT with Diode



| Combi Pack |  | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| Symbol | Test Conditions |  |  |
| $\mathrm{V}_{\text {ces }}$ | $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 600 | V |
| $\mathrm{V}_{\text {cGr }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C} ; \mathrm{R}_{\mathrm{GE}}=1 \mathrm{M} \Omega$ | 600 | V |
| $\mathrm{V}_{\text {GES }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GEM }}$ | Transient | $\pm 30$ | V |
| $\mathrm{I}_{\mathrm{C} 25}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 76 | A |
| $\mathrm{I}_{\text {c90 }}$ | $\mathrm{T}_{\mathrm{c}}=90^{\circ} \mathrm{C}$ | 38 | A |
| $\mathrm{I}_{\text {cm }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, 1 \mathrm{~ms}$ | 152 | A |
| $\begin{aligned} & \text { SSOA } \\ & \text { (RBSOA) } \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V}, \mathrm{~T}_{\mathrm{VV}}=125^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{G}}=10 \Omega \\ & \text { Clamped inductive load, } \mathrm{L}=100 \mu \mathrm{H} \end{aligned}$ | $\begin{array}{r} \mathrm{I}_{\mathrm{CM}}=76 \\ @ 0.8 \mathrm{~V}_{\text {CES }} \\ \hline \end{array}$ | A |
| $\mathrm{P}_{\mathrm{c}}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 200 | w |
| TJ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{Jm}}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| M ${ }_{\text {d }}$ | Mounting torque (M3) | 1.13/10 | Nm/lb.in. |
| Weight |  | 6 | g |
| Maximum 1.6 mm (0. | ad temperature for soldering 2 in.) from case for 10 s | 300 | ${ }^{\circ} \mathrm{C}$ |


| Symbol | Test Conditions | Characteristic Values ( $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. $^{\text {ty }}$ max. |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $B V_{\text {ces }}$ | $\mathrm{I}_{\mathrm{C}}=750 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{GE}}=0 \mathrm{~V}$ | 600 |  |  | V |
| $\mathrm{V}_{\text {GE(th) }}$ | $\mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=\mathrm{V}_{\mathrm{GE}}$ | 2.5 |  | 5.5 | V |
| $I_{\text {ces }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=0.8 \cdot \mathrm{~V}_{\mathrm{CES}} \\ & \mathrm{~V}_{\mathrm{GE}}=0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C} \end{aligned}$ |  | 500 8 | $\begin{aligned} & \mu \mathrm{A} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\text {GES }}$ | $\mathrm{V}_{\mathrm{CE}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GE}}= \pm 20 \mathrm{~V}$ |  |  | $\pm 100$ | nA |
| $\mathrm{V}_{\text {CE(sat) }}$ | $\mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\mathrm{C90}}, \mathrm{~V}_{\mathrm{GE}}=15 \mathrm{~V}$ |  |  | 1.8 | V |

TO-247 AD


G = Gate, $\mathrm{E}=$ Emitter,

C = Collector, TAB = Collector

## Features

- International standard package JEDEC TO-247 AD
- IGBT and anti-parallel FRED in one package
- 2nd generation $\mathrm{HDMOS}^{T M}$ process
- Low $\mathrm{V}_{\mathrm{CE}(\text { sat })}$
- for minimum on-state conduction losses
- MOS Gate turn-on
- drive simplicity
- Fast Recovery Epitaxial Diode (FRED)
- soft recovery with low $I_{\text {RM }}$


## Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies


## Advantages

- Space savings (two devices in one package)
- Easy to mount with 1 screw (isolated mounting screw hole)
- Reduces assembly time and cost
- High power density

| Symbol | Test Conditions <br> Characteristic Values ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. max. |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{g}_{\text {Is }}$ | $I_{C}=I_{\text {C90 }} ; \mathrm{V}_{\text {CE }}=10 \mathrm{~V}$, <br> Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle $\leq 2 \%$ | 20 | S |
| $\begin{aligned} & \mathrm{C}_{\text {ies }} \\ & \mathrm{C}_{\text {oes }} \\ & \mathrm{C}_{\text {res }} \end{aligned}$ | $\int \mathrm{V}_{\mathrm{CE}}=25 \mathrm{~V}, \mathrm{~V}_{\mathrm{GE}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | $\begin{array}{r} 2500 \\ 270 \\ 70 \end{array}$ | pF pF pF |
| $\begin{aligned} & \mathbf{Q}_{\mathrm{g}} \\ & \mathbf{Q}_{\mathrm{ge}} \\ & \mathbf{Q}_{\mathrm{gc}} \end{aligned}$ | \} $\mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\text {c90 }}, \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CE}}=0.5 \mathrm{~V}_{\text {CES }}$ | $\begin{array}{r} 125 \\ 23 \\ 50 \end{array}$ | $\begin{array}{rl} 150 & \mathrm{nC} \\ 35 & \mathrm{nC} \\ 75 & \mathrm{nC} \end{array}$ |
| $\begin{aligned} & t_{\mathrm{d}(0 n)} \\ & t_{t_{i \mathrm{i}}} \\ & t_{\mathrm{d}(\mathrm{fft})} \\ & t_{\mathrm{ti}} \\ & E_{\mathrm{off}} \end{aligned}$ | Inductive load, $\mathrm{T}_{\mathrm{J}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\mathrm{Cog}}, \mathrm{~V}_{\text {GE }}=15 \mathrm{~V}, \mathrm{~L}=100 \mu \mathrm{H}, \\ & \mathrm{~V}_{\mathrm{CE}}=0.8 \mathrm{VV}_{\mathrm{CES}}, \mathrm{R}_{\mathrm{G}}=\mathrm{R}_{\mathrm{off}}=10 \Omega \end{aligned}$ <br> Remarks: Switching times may increase for $\mathrm{V}_{\mathrm{CE}}$ (Clamp) $>0.8 \cdot \mathrm{~V}_{\text {CES }}$, higher $\mathrm{T}_{J}$ or increased $\mathrm{R}_{\mathrm{G}}$ | $\begin{array}{r} 30 \\ 150 \\ 600 \\ 500 \\ 9 \end{array}$ | $\begin{array}{rl} 1200 & \mathrm{~ns} \\ 700 & \mathrm{~ns} \\ 15 & \mathrm{~mJ} \end{array}$ |
| $t_{\text {d(on) }}$ $t_{\text {ti }}$ $E_{\text {on }}$ $t_{\text {doft }}$ $t_{\text {tiif }}$ $E_{\text {off }}$ | Inductive load, $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=\mathrm{I}_{\mathrm{C} 90}, \mathrm{~V}_{\mathrm{GE}}=15 \mathrm{~V}, \mathrm{~L}=100 \mu \mathrm{H} \\ & \mathrm{~V}_{\mathrm{CE}}=0.8 \mathrm{~V}_{\mathrm{CES}}, \mathrm{R}_{\mathrm{G}}=\mathrm{R}_{\mathrm{off}}=10 \Omega \end{aligned}$ <br> Remarks: Switching times may increase for $\mathrm{V}_{\text {CE }}($ Clamp $)>0.8 \cdot \mathrm{~V}_{\text {CES }}$, higher $\mathrm{T}_{\mathrm{J}}$ or increased $R_{G}$ | $\begin{array}{r} 40 \\ 160 \\ 1 \\ 800 \\ 1000 \\ 15 \end{array}$ | ns |
| $\begin{aligned} & \mathbf{R}_{\mathrm{truc}} \\ & \mathbf{R}_{\mathrm{trck}} \end{aligned}$ |  | 0.25 | $\begin{array}{r} 0.62 \mathrm{~K} / \mathrm{W} \\ \mathrm{~K} / \mathrm{W} \end{array}$ |

## Reverse Diode (FRED)

Characteristic Values

| Symbol | ( $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$, unless otherwise specified) |  |  |
| :---: | :---: | :---: | :---: |
|  | Test Conditions min. | typ. | max. |
| $\mathrm{V}_{\mathrm{F}}$ | $I_{F}=I_{c 90}, V_{G E}=0 \mathrm{~V},$ <br> Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle $\mathrm{d} \leq 2 \%$ |  | 1.6 |
|  |  | $\begin{array}{r} 10 \\ 150 \\ 35 \end{array}$ | $\begin{array}{cc} 15 & \text { A } \\ & \text { ns } \\ 50 & \text { ns } \end{array}$ |
| $\mathrm{R}_{\text {thuc }}$ |  |  | $1 \mathrm{~K} / \mathrm{W}$ |



